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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/772,029	02/03/2004	Michael Pelham	TRAN-P151	3885
7590 11/20/2006		EXAMINER		
-	URABITO & HAO LL	LUU, CHUONG A		
Two North Marl San Jose, CA	ket Street, Third Floor 95113		ART UNIT	PAPER NUMBER
<b>San Coo</b> c, 200			2818	
			DATE MAIL ED. 11/20/200	c

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application No.	Applicant(s)	
Office Action Summary		10/772,029	PELHAM ET AL.	
		Examiner	Art Unit	
		Chuong A. Luu	2818	
Period fo	The MAILING DATE of this communicator Reply	tion appears on the cover she	et with the correspondence add	dress
WHI( - Exte after - If NC - Failu Any	ORTENED STATUTORY PERIOD FOR CHEVER IS LONGER, FROM THE MAIL assions of time may be available under the provisions of 30 SIX (6) MONTHS from the mailing date of this communic period for reply is specified above, the maximum statutore to reply within the set or extended period for reply will, reply received by the Office later than three months after the patent term adjustment. See 37 CFR 1.704(b).	LING DATE OF THIS COMM 7 CFR 1.136(a). In no event, however, nutrition.  Try period will apply and will expire SIX (6 by statute, cause the application to become	UNICATION.  nay a reply be timely filed  ) MONTHS from the mailing date of this come ABANDONED (35 U.S.C. § 133).	,
Status				
1)⊠ 2a)□ 3)□	Responsive to communication(s) filed of This action is <b>FINAL</b> . 2b). Since this application is in condition for closed in accordance with the practice of	☐ This action is non-final.     allowance except for formal		merits is
Disposit	ion of Claims			
5)□ 6)⊠ 7)⊠ 8)□ <b>Applicat</b> 9)□ 10)□	Claim(s) 1-5 and 8 is/are pending in the 4a) Of the above claim(s) is/are versions [15]. Claim(s) is/are allowed.  Claim(s) 1-4 and 8 is/are rejected.  Claim(s) 5 is/are objected to.  Claim(s) are subject to restriction [15].  Claim(s) are subject to restriction [15].  Claim(s) are subject to by the E. The drawing(s) filed on is/are: a)  Applicant may not request that any objection [15]. Replacement drawing sheet(s) including the The oath or declaration is objected to by	withdrawn from consideration and/or election requirement warminer.  accepted or b) objected to the drawing(s) be held in able correction is required if the drawing the drawin	t. d to by the Examiner. seyance. See 37 CFR 1.85(a). wing(s) is objected to. See 37 CF	
		the Examiner. Note the atta	ched Office Action of form F1	O-132.
12)□ a)l	Acknowledgment is made of a claim for All b) Some * c) None of:  1. Certified copies of the priority doc 2. Certified copies of the priority doc 3. Copies of the certified copies of the application from the International see the attached detailed Office action for	cuments have been received cuments have been received he priority documents have b Bureau (PCT Rule 17.2(a)).	in Application No been received in this National S	Stage
2)  Notic 3)  Inforr	t(s) e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (PTO- nation Disclosure Statement(s) (PTO-1449 or PTC r No(s)/Mail Date	948) Paper	iew Summary (PTO-413) · No(s)/Mail Date e of Informal Patent Application (PTO :	-152)

Art Unit: 2818

### **DETAILED ACTION**

# Response to Arguments

Applicant's arguments with respect to claims 1-5 and 8 have been considered but are most in view of the new ground(s) of rejection.

#### PRIOR ART REJECTIONS

## **Statutory Basis**

# Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

## The Rejections

Claims 1-5 and 8 are rejected under 35 U.S.C. 102(b) as being anticipated by Sakai (U.S. 4,907,058).

Sakai discloses a complementary semiconductor device with

(1) specifying a tile comprising a first layer wherein said first layer comprises a first layer element for a deep N-well pattern;

Application/Control Number: 10/772,029

Art Unit: 2818

arranging multiple instances of said tile to create a tile array covering a portion of said integrated circuit design;

merging said tiles to produce a deep N-well pattern (see Figure 2B);

- (2) wherein said tile further comprises a second layer, wherein said second layer comprises a second layer element (see Figure 2B);
- (3) wherein said first layer element is identical in shape to said second layer element (see Figure 2B);
- (4) wherein said first layer element is disposed rotated with respect to said second layer element (see Figure 2B);
- (8) further comprising flattening said first layer and said second layer (see Figure 2B).

Claims 1-5 and 8 are rejected under 35 U.S.C. 102(b) as being anticipated by Masleid et al. (U.S. 7,049,699).

Masleid discloses a low RC structure with

(1) specifying a tile comprising a first layer wherein said first layer comprises a first layer element for a deep N-well pattern;

arranging multiple instances of said tile to create a tile array covering a portion of said integrated circuit design;

merging said tiles to produce a deep N-well pattern (see Figures 5A-5B);

(2) wherein said tile further comprises a second layer, wherein said second layer comprises a second layer element (see Figures 5A-5B);

(3) wherein said first layer element is identical in shape to said second layer element (see Figures 5A-5B);

- (4) wherein said first layer element is disposed rotated with respect to said second layer element (see Figures 5A-5B);
- (8) further comprising flattening said first layer and said second layer (see Figures 5A-5B).

# Allowable Subject Matter

Claim 5 is objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

#### Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Chuong A. Luu whose telephone number is (571) 272-1902. The examiner can normally be reached on M-F (6:15-2:45).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Matthew Smith can be reached on (571) 272-1907. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Application/Control Number: 10/772,029

Art Unit: 2818

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system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

Chuong Anh Luu Patent Examiner November 01, 2006 Page 5